



Single 4:1 Low r_{ON} Multiplexers

DESCRIPTION

The DG2034 is a low voltage, low r_{ON} , high bandwidth single 4 to 1 analog multiplexer designed for high performance switching of analog and video signals. Combining low power; fast switching; low on-resistance, flatness and matching; and small physical size, the DG2034 is ideal for portable and battery applications.

Built on Vishay Siliconix's low voltage CMOS process, the DG2034 has an epitaxial layer which prevents latchup. Break-before-make is guaranteed.

FEATURES

- Low voltage operation (1.8 V to 5.5 V)
- Low on-resistance - $r_{DS(on)}$: 4 Ω
- Off-isolation and crosstalk: - 55 dB at 10 MHz
- Fast switch - 25 ns t_{ON}
- Low charge injection - Q_{INJ} : 4.7 pC
- Low power consumption - 4 μ W



RoHS COMPLIANT

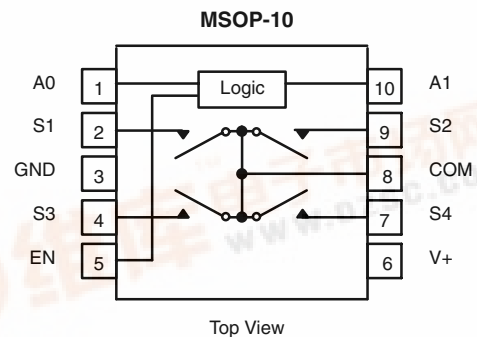
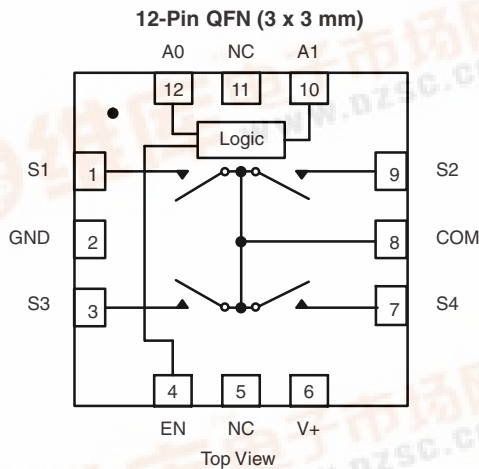
BENEFITS

- High accuracy
- High bandwidth
- TTL and low voltage logic compatibility
- Low power consumption
- Reduced PCB space

APPLICATIONS

- Mixed signal routing
- Portable and battery operated systems
- Low voltage data acquisition
- Modems
- PCMCIA cards

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

A1	A0	EN	ON Switch
X	X	0	None
0	0	1	S1
0	1	1	S2
1	0	1	S3
1	1	1	S4

ORDERING INFORMATION

Temp Range	Package	Part Number
- 40 °C to 85 °C	MSOP-10	DG2034DQ-T1-E3
	12-pin QFN (3 x 3 mm)	DG2034DN-T1-E4





ABSOLUTE MAXIMUM RATINGS			
Parameter	Limit		Unit
Referenced V+ to GND	- 0.3 to + 6		V
A _X , E _N , S _X , COM ^a	- 0.3 to (V+ + 0.3)		
Continuous Current (Any Terminal)	± 50		mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)	± 100		
Power Dissipation (Packags) ^b	QFN-12 (3 x 3 mm) ^c	1295	mW
	MSOP-10 ^d	320	
Storage Temperature (D Suffix)	- 65 to 150		°C

Notes:

- a. Signals on S_X, D_X, EN or A_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 16.2 mW/°C above 70 °C.
- d. Derate 4.0 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V _{AL} = 0.4 V, V _{AH} = 1.5 V ^e	Temp. ^a	Limits - 40 to 85 °C			Unit
				Min. ^c	Typ. ^b	Max. ^c	
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	0		V+	V
On-Resistance	r _{ON}	V+ = 2.7 V, V _{COM} = 0.5 V/1.5 V/2.0 V I _S = 10 mA	Room Full		4	7 9	Ω
r _{ON} Match	Δr _{ON}		Room		0.1	0.3	
r _{ON} Flatness ^{d,f}	r _{ON} Flatness		Room		0.3	1.5	
Off Leakage Current ^g	I _{S(off)}	V+ = 3.3 V, V _S = 1 V/3 V V _{COM} = 3 V/1 V, V _{EN} = 0 V	Room Full	- 1 - 10	0.3	1 10	nA
COM Off Leakage Current ^g	I _{COM(off)}		Room Full	- 1 - 10	0.3	1 10	
Channel-On Leakage Current ^g	I _{COM(on)}		Room Full	- 1 - 10	0.3	1 10	
Digital Control							
Input Current ^d	I _A or I _{EN}	V _{A/EN} = 0 or V+, See Truth Table	Full	- 1.0		1.0	μA
Input High Voltage ^d	V _{AH} or V _{ENH}		Full	1.5			V
Input Low Voltage ^d	V _{AL} or V _{ENL}		Full			0.4	
Dynamic Characteristics							
Turn-On Time	t _{ON}	V _S = 1.5 V, R _L = 300 Ω	Room Full		25	35 45	ns
Turn-Off Time	t _{OFF}		Room Full		15	25 35	
Break-Before-Make Time ^d	t _D		Room		10.5		
Transition Time	t _{trans}	V _S = 1.5 V/0 V, V _S = 0 V/1.5 V, R _L = 300 Ω	Room Full		30	45 55	
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{gen} = 0 V, R _{gen} = 0 Ω	Room		- 4.7		pC
Off-Isolation ^d	OIRR	R _L = 50 Ω, C _L = 5 pF	f = 1 MHz	Room		- 73	dB
			f = 10 MHz	Room		- 54	
Channel-to-Channel Crosstalk ^d	X _{TALK}	R _L = 50 Ω, C _L = 5 pF	f = 1 MHz	Room		- 77	
			f = 10 MHz	Room		- 59	
Off Capacitance ^d	C _{S(off)}	V+ = 2.7 V, f = 1 MHz	Room		14		pF
COM Off Capacitance ^d	C _{COM(off)}		Room		46		
COM On Capacitance ^d	C _{COM(on)}		Room		67		
Power Supply							
Power Supply Range	V+			2.7		3.3	V
Power Supply Current ^d	I+	V+ = 3.3 V, V _{A/EN} = 0 or 3.3 V, See Truth Table	Full			1.0	μA



SPECIFICATIONS (V+ = 5 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V _{AL} = 0.8 V or V _{AH} = 2.4 V ^e	Temp. ^a	Limits - 40 to 85 °C			Unit
				Min. ^c	Typ. ^b	Max. ^c	
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	0		V+	V
On-Resistance	r _{ON}	V+ = 4.5 V, V _{COM} = 1.5 V/2.5 V/3.5 V I _S = 10 mA	Room Full		3	5.5 7	Ω
r _{ON} Match	Δr _{ON}		Room		0.16	0.5	
r _{ON} Flatness ^{d,f}	r _{ON} Flatness		Room		0.6	1.5	
Off Leakage Current	I _{S(off)}	V+ = 5.5 V, V _S = 1 V/4.5 V V _{COM} = 4.5 V/1 V, V _{EN} = 0 V	Room Full	- 1 - 10	0.5	1 10	nA
COM Off Leakage Current	I _{COM(off)}		Room Full	- 1 - 10	0.5	1 10	
Channel-On Leakage Current	I _{COM(on)}	V+ = 5.5 V, V _{COM} = V _S = 1 V/4.5 V	Room Full	- 1 - 10	0.5	1 10	
Digital Control							
Input Current ^d	I _{AH} or I _{ENH}	V _A or V _{EN} = 0 or V+, See Truth Table	Full	- 1.0		1.0	μA
Input High Voltage ^d	V _{AH} or V _{ENH}		Full	2.4			V
Input Low Voltage ^d	V _{AL} or V _{ENL}		Full			0.8	
Dynamic Characteristics							
Turn-On Time	t _{ON}	V _S = 3.0 V, R _L = 300 Ω	Room Full		18	30 40	ns
Turn-Off Time	t _{OFF}		Room Full		12	20 30	
Break-Before-Make Time ^d	t _D		Room		10.5		
Transition Time	t _{trans}	V _S = 3 V/0 V, V _S = 0 V/3 V, R _L = 300 Ω	Room Full		25	40 50	
Off-Isolation ^d	OIRR	R _L = 50 Ω, C _L = 5 p	f = 1 MHz	Room		- 73	dB
			f = 10 MHz	Room		- 53.5	
Channel-to-Channel Crosstalk ^d	X _{TALK}	R _L = 50 Ω, C _L = 5 pF	f = 1 MHz	Room		- 77	
			f = 10 MHz	Room		- 60.2	
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, V _{gen} = 0 V, R _{gen} = 0 Ω	Room		- 4.4		pC
Off Capacitance ^d	C _{S(off)}	V+ = 5 V, f = 1 MHz	Room		13		pF
COM Off Capacitance ^d	C _{COM(off)}		Room		43		
COM On Capacitance ^d	C _{COM(on)}		Room		64		
Power Supply							
Power Supply Range	V+			4.5		5.5	V
Power Supply Current	I+	V+ = 5.5 V, V _{AVEN} = 0 or 5.5 V, See Truth Table	Full			1.0	μA

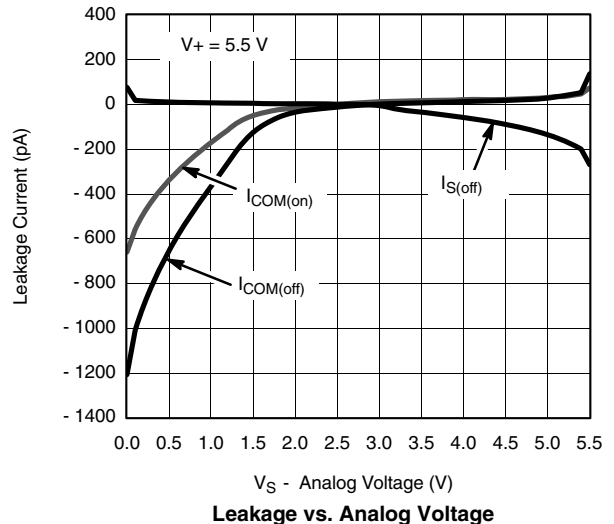
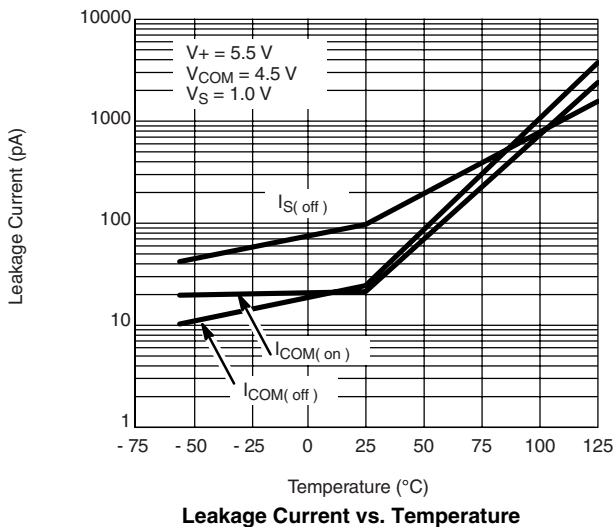
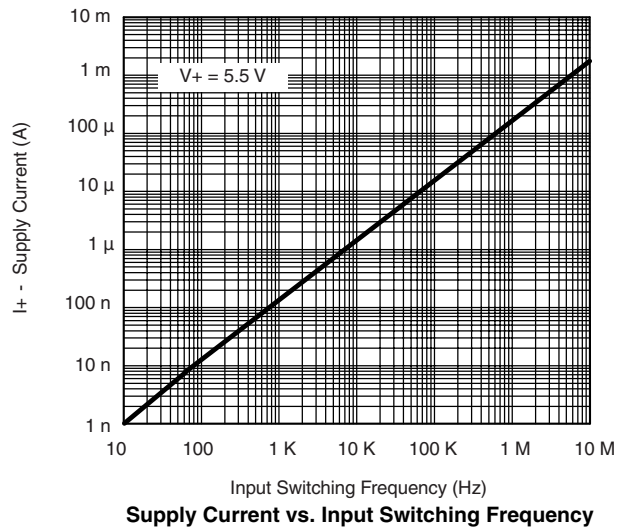
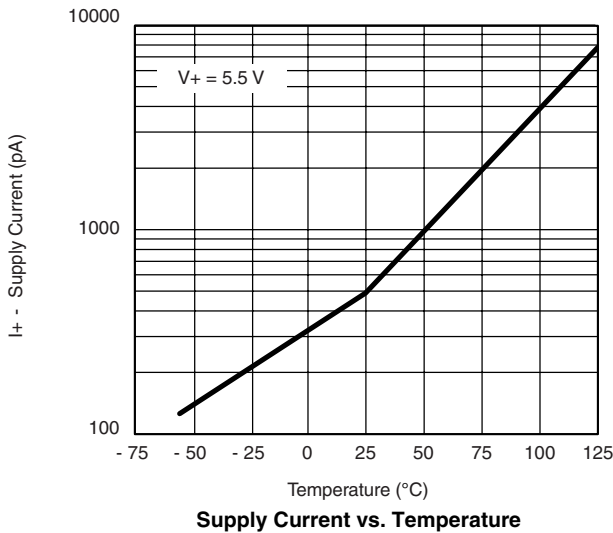
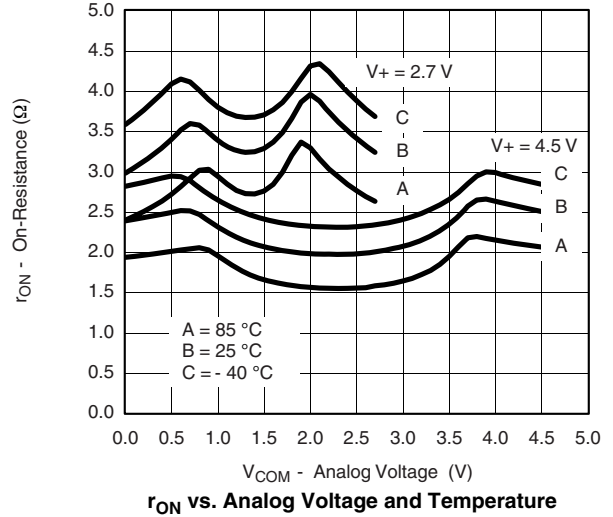
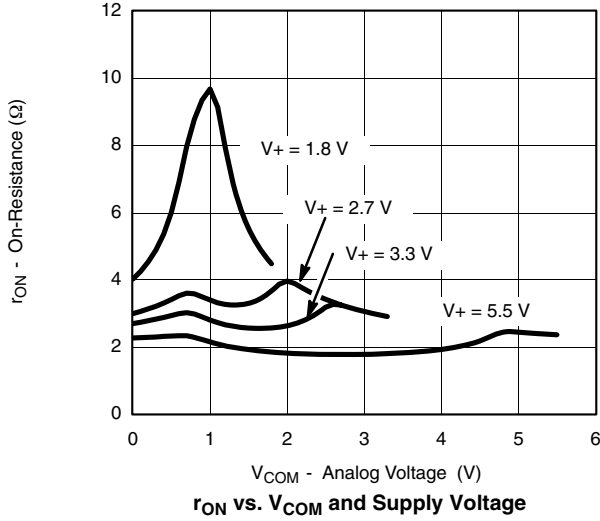
Notes:

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. Typical values are for design aid only, not guaranteed nor subject to production testing.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- d. Guarantee by design, not subjected to production test.
- e. V_A, E_N = input voltage to perform proper function.
- f. Difference of min and max values.
- g. Guaranteed by 5 V testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

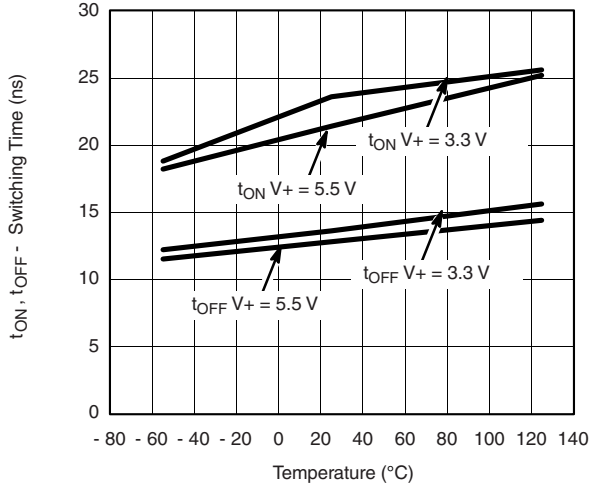


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

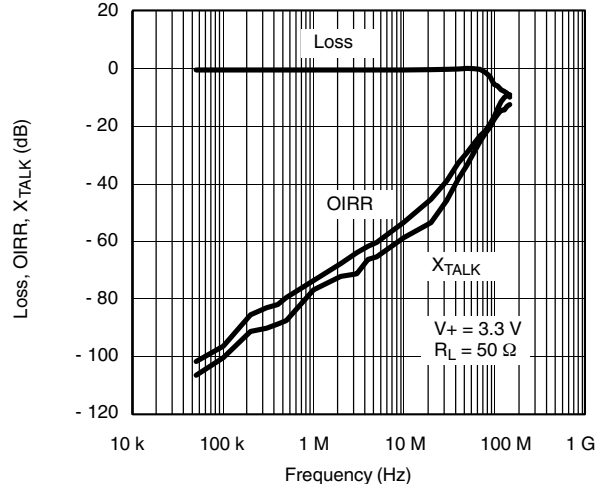




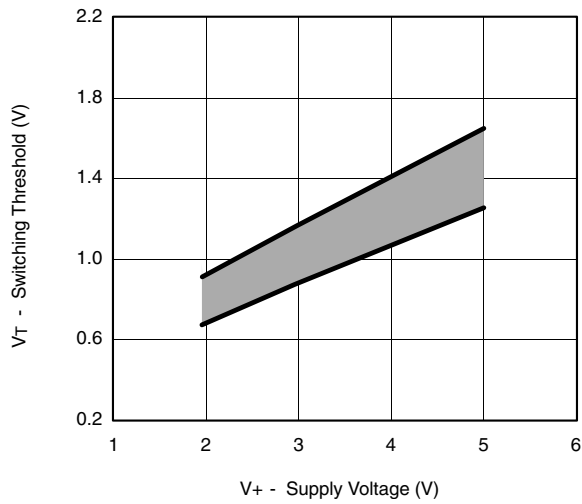
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



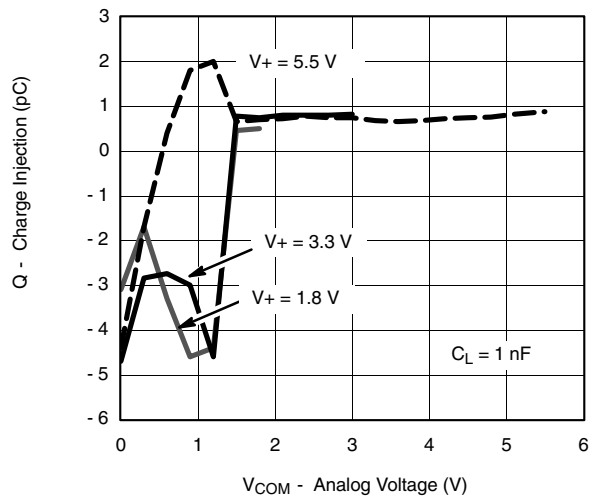
Switching Time vs. Temperature



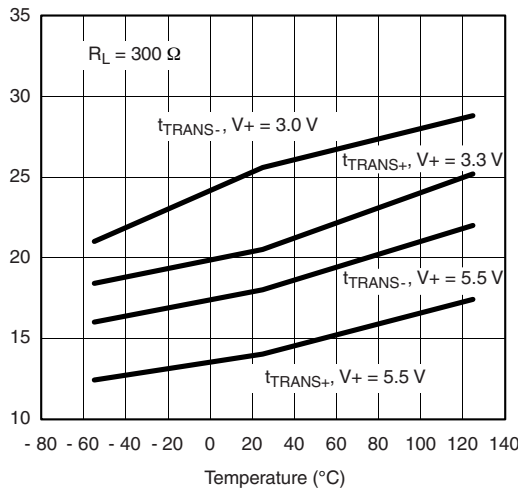
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Switching Threshold vs. Supply Voltage

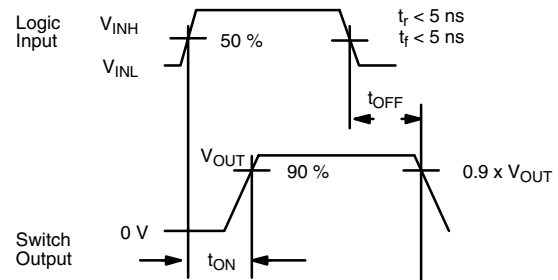
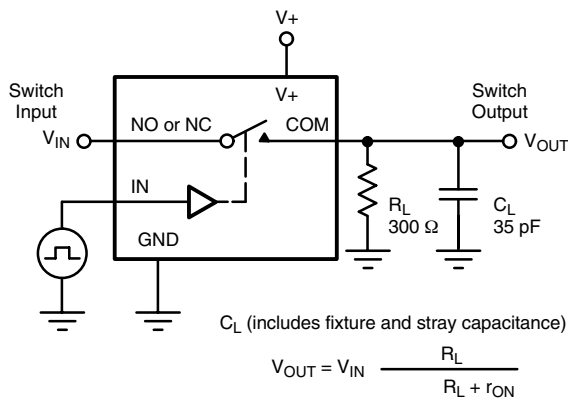


Charge Injection vs. Analog Voltage



Transition Time vs. Temperature

TEST CIRCUITS



Note: Logic input waveform is inverted for switches that have the opposite logic sense control

Figure 1. Switching Time

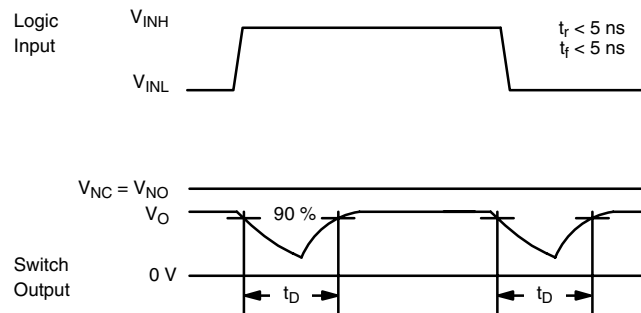
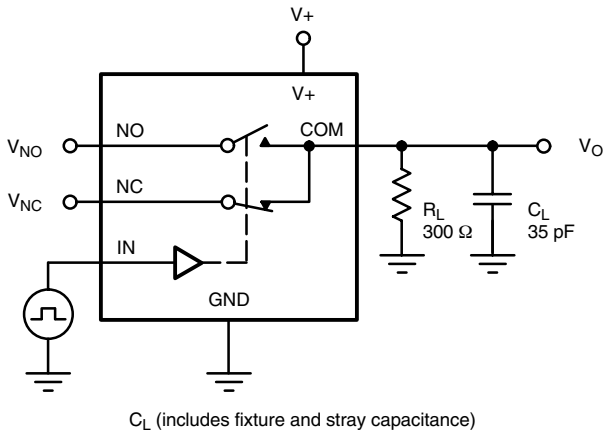


Figure 2. Break-Before-Make

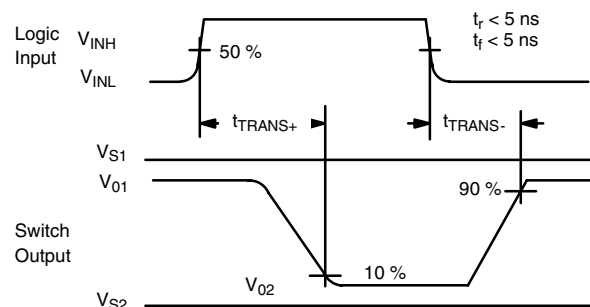
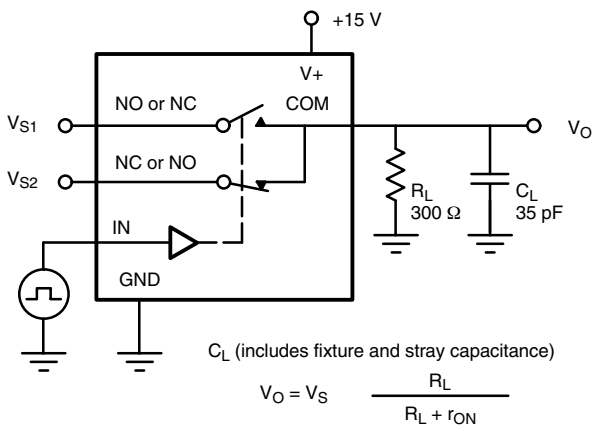
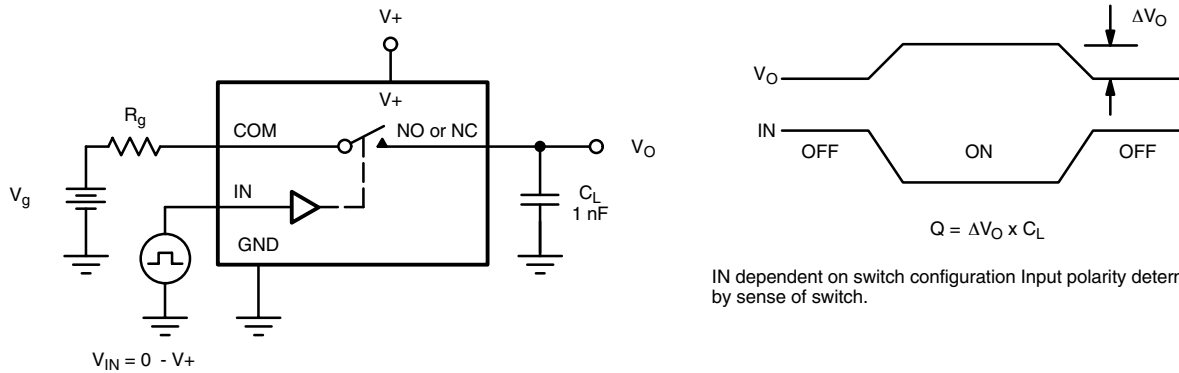
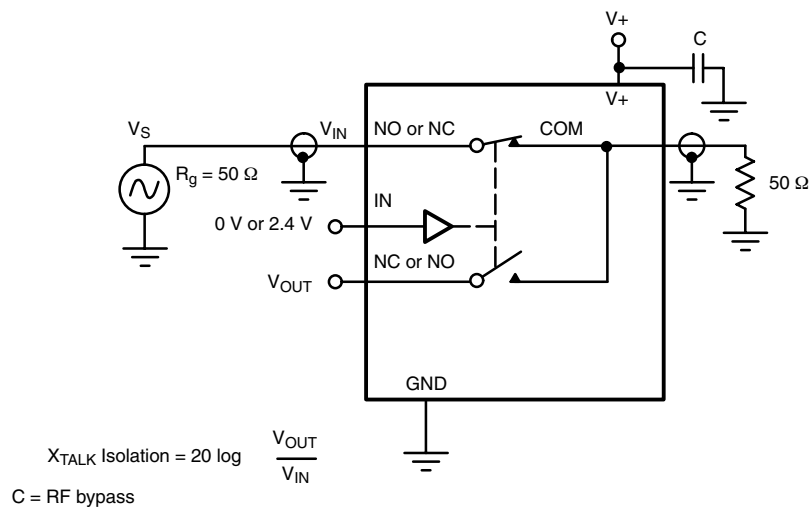
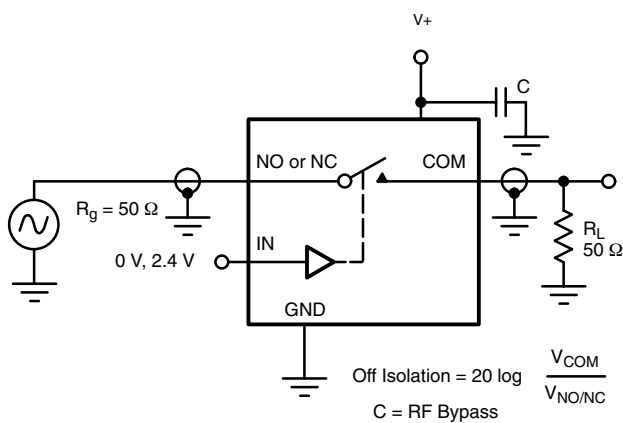
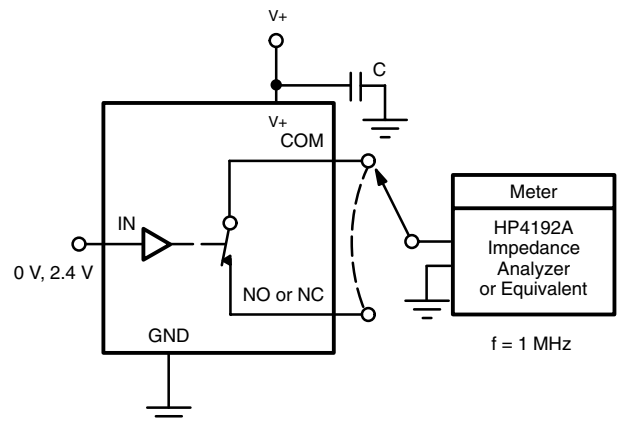


Figure 3. Transition Time

TEST CIRCUITS

Figure 4. Charge Injection

Figure 5. Crosstalk

Figure 6. Off Isolation

Figure 7. Source/Drain Capacitances



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.